
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Koos et al.

Application No.: 10/690,084

Filed: October 20, 2003

Title: METHOD FOR FABRICATION OF
SEMICONDUCTOR INTERCONNECT
STRUCTURE WITH REDUCED
CAPACITANCE, LEAKAGE CURRENT, AND
IMPROVED BREAKDOWN VOLTAGE

Attorney Docket No.: **RECEIVED**
NOVLP068/NVLS-2818 **CENTRAL FAX CENTER****AUG 28 2007**

Examiner: Vinh, Lan

Group: 1765

CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being transmitted by
facsimile to fax number 571-273-8300 of the U.S. Patent and
Trademark Office on August 28, 2007.

Signed: 

Mary Terry

AMENDMENT E

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

This is in response to the non-final Office Action mailed August 02, 2007.

Listing of claims begins on page 2 of this paper.

Remarks begin on page 9 of this paper.